X-ray Study of the Valence Transition of CeOs₄Sb₁₂ in Pulsed Magnetic Fields

Matthew J. Pearce^{1,2}, Kathrin Götze^{1,3}, Paul A. Goddard¹

¹ Department of Physics, University of Warwick, Coventry, CV4 7AL, UK

² Department of Physics, University of Oxford, Oxford, OX1 3PU, UK

³ Deutsches Elektronen-Synchrotron (DESY), Hamburg, 22607, Germany

Zahirul Islam⁴, Ulrich Welp⁴ ⁴ Argonne National Laboratory, Argonne, 60439, USA

Roger D. Johnson^{5,6}, Pascal Manuel⁵ ⁵ ISIS Facility, Rutherford Appleton Laboratory, Chilton, OX11 0QX, UK ⁶ Department of Physics and Astronomy, UCL, London, WC1E 6BT, UK

M. Brian Maple⁷ ⁷ Department of Physics, University of California, San Diego, La Jolla, 92093, USA

Pei-Chun Ho⁸ ⁸ Department of Physics, California State University, Fresno, 93740, USA

John Singleton⁹

⁹ National High Magnetic Field Laboratory, Los Alamos National Laboratory, Los Alamos, 87545, USA

Valence transitions, where f electrons undergo a transformation from quasi-localised to itinerant, are associated with a change in unit cell volume. Perhaps the most famous and dramatic example of this is the $\gamma - \alpha$ transition in cerium and its alloys, which for elemental cerium is accompanied by an isostructural collapse of the unit cell volume often reported to be as large as ~15 % [1]. The Ce-based compound CeOs₄Sb₁₂ has previously been shown using resistivity, magnetostriction, and contactless conductivity (PDO) measurements to undergo a valence transition from the high-temperature, high-field \mathcal{H} -phase to the low-temperature, low-field \mathcal{L} -phase with a very unusually-shaped phase boundary [2, 3]. In this seminar I will discuss the results of single-crystal x-ray diffraction measurements in pulsed magnetic fields of up to 30 T performed to study this valence transition at a microscopic level. We observe a field-induced change of the lattice parameter associated with the transition from the previously reported cubic structure. The observation of both of these subtle effects is only possible due to the high sensitivity of the backscattering geometry used.

M. J. P. acknowledges support from the European Research Council (ERC) under the European Union's Horizon 2020 research and innovation programme Grant Agreement Numbers 788814 (EQFT) and 681260, and the EPSRC (UK) under Grant No. EP/N509796/1. This research used resources of the Advanced Photon Source, a U.S. Department of Energy (DOE) Office of Science User Facility operated for the DOE Office of Science by Argonne National Laboratory under Contract No. DE-AC02-06CH11357. High-field pulsed magnet and a choke coil were installed at the Advanced Photon Source through a partnership with the International Collaboration Center at the Institute for Materials Research (ICC-IMR) and Global Institute for Materials Research Tohoku (GIMRT) at Tohoku University.

[1] D. C. Koskenmaki and K. A. Gschneider, in Handbook on the physics and chemistry of rare earths, eds K. A. Gschneider and L. Eyring (North Holland, Amsterdam, 1978), vol. 1, pp. 343–353

[2] K. Götze *et al.*, Unusual phase boundary of the magnetic-field-tuned valence transition in CeOs₄Sb₁₂, *Phys. Rev. B* **101**, 075102 (2020).

[3] K. Götze *et al.*, Pressure-induced shift of effective Ce valence, Fermi energy and phase boundaries in CeOs₄Sb₁₂, *New. J. Phys.* **24**, 043044 (2022).